

## High Speed 10MBit/s Logic Gate Optocouplers

### Description

The UMW 6N137 optocoupler consists of a 850 nm AlGaAs LED, optically coupled to a very high speed integrated photo-detector logic gate with strobable output. This output features an open collector, thereby permitting wired OR outputs. The coupled parameters are guaranteed over the temperature range of -40 °C to +85 °C. A maximum input signal of 5mA will provide a minimum output sink current of 13mA (fan out of 8).

An internal noise shield provides superior common mode rejection of typically 10kV/μs. The UMW 6N137 has a minimum CMR of 5kV/μs.

### Features

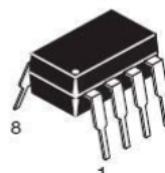
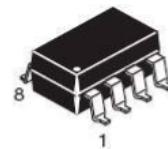
- Very high speed – 10 MBit/s
- Superior CMR – 10 kV/μs
- Double working voltage-480V
- Fan-out of 8 over -40 °C to +85 °C
- Logic gate output
- Strobable output
- Wired OR-open collector
- UL approved: UL1577, file No. E492440

### Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5-volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer-peripheral interface

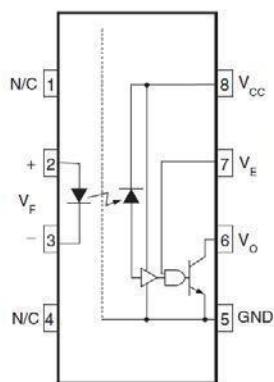
**Truth Table (Positive Logic)**

Input	Enable	Output
H	H	L
L	H	H
H	L	H
L	L	H
H	NC	L
L	NC	H



### Package Outlines

### Schematics



## High Speed 10MBit/s Logic Gate Optocouplers

### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
$T_{STG}$	Storage Temperature	-55 to +125	$^\circ\text{C}$
$T_{OPR}$	Operating Temperature	-40 to +85	$^\circ\text{C}$
$T_{SOL}$	Lead Solder Temperature (for wave soldering only)	260 for 10 sec	$^\circ\text{C}$
<b>EMITTER</b>			
$I_F$	DC/Average Forward Input Current	50	mA
$V_E$	Enable Input Voltage Not to Exceed $V_{CC}$ by more than 500mV	5.5	V
$V_R$	Reverse Input Voltage	5.0	V
$P_I$	Power Dissipation	100	mW
<b>DETECTOR</b>			
$V_{CC}$ (1 minute max)	Supply Voltage	7.0	V
$I_O$	Output Current	50	mA
$V_O$	Output Voltage	7.0	V
$P_O$	Collector Output	85	mW

### Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. We do not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
$I_{FL}$	Input Current, Low Level	0	250	$\mu\text{A}$
$I_{FH}$	Input Current, High Level	*6.3	15	mA
$V_{CC}$	Supply Voltage, Output	4.5	5.5	V
$V_{EL}$	Enable Voltage, Low Level	0	0.8	V
$V_{EH}$	Enable Voltage, High Level	2.0	$V_{CC}$	V
$T_A$	Low Level Supply Current	-40	+85	$^\circ\text{C}$
N	Fan Out (TTL load)		8	

Note: \*6.3mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0mA or less.

## High Speed 10MBit/s Logic Gate Optocouplers

**Electro-optical Characteristics (T<sub>A</sub>= 0 to 70 °C unless otherwise specified)**

### Individual Component Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.*	Max.	Unit
<b>EMITTER</b>						
V <sub>F</sub>	Input Forward Voltage	I <sub>F</sub> = 10mA	T <sub>A</sub> = 25 °C	1.4	1.75	1.8
B <sub>VR</sub>	Input Reverse Breakdown Voltage	I <sub>R</sub> = 10 µA		5.0		V
C <sub>IN</sub>	Input Capacitance	V <sub>F</sub> = 0, f = 1MHz		60		pF
ΔV <sub>F</sub> /ΔT <sub>A</sub>	Input Diode Temperature Coefficient	I <sub>F</sub> = 10mA		-1.4		mV/°C
<b>DETECTOR</b>						
I <sub>CCH</sub>	High Level Supply Current	V <sub>CC</sub> = 5.5V, I <sub>F</sub> = 0mA, V <sub>E</sub> = 0.5V		7	10	mA
I <sub>CCL</sub>	Low Level Supply Current	V <sub>CC</sub> = 5.5V, I <sub>F</sub> = 10mA		9	13	mA
I <sub>EL</sub>	Low Level Enable Current	V <sub>CC</sub> = 5.5V, V <sub>E</sub> = 0.5V		-0.8	-1.6	mA
I <sub>EH</sub>	High Level Enable Current	V <sub>CC</sub> = 5.5V, V <sub>E</sub> = 2.0V		-0.6	-1.6	mA
V <sub>EH</sub>	High Level Enable Voltage	V <sub>CC</sub> = 5.5V, I <sub>F</sub> = 10mA	2.0			V
V <sub>EL</sub>	Low Level Enable Voltage	V <sub>CC</sub> = 5.5V, I <sub>F</sub> = 10mA <sup>(5)</sup>			0.8	V

**Switching Characteristics (T<sub>A</sub> -40 °C to +85 °C, V<sub>CC</sub> = 5V, I<sub>F</sub> = 7.5mA unless otherwise specified)**

Symbol	AC Characteristics	Test Conditions	Min.	Typ.*	Max.	Unit
T <sub>PLH</sub>	Propagation Delay Time to Output HIGH Level	R <sub>L</sub> = 350 Ω , C <sub>L</sub> =15pF <sup>(4)</sup> (Fig. 12)	TA = 25 °C	20	45	75
						100 ns
T <sub>PHL</sub>	Propagation Delay Time to Output LOW Level	TA = 25 °C <sup>(5)</sup>	25	45	75	ns
		R <sub>L</sub> = 350 Ω , C <sub>L</sub> =15pF (Fig. 12)			100	
T <sub>PHL</sub> - T <sub>PLH</sub>	Pulse Width Distortion	(R <sub>L</sub> = 350 Ω , C <sub>L</sub> =15pF (Fig. 12))		3	35	ns
t <sub>r</sub>	Output Rise Time (10–90%)	R <sub>L</sub> = 350 Ω , C <sub>L</sub> =15pF <sup>(6)</sup> (Fig. 12)		50		ns
t <sub>f</sub>	Output Fall Time (90–10%)	R <sub>L</sub> = 350 Ω , C <sub>L</sub> =15pF <sup>(7)</sup> (Fig. 12)		12		ns
t <sub>ELH</sub>	Enable Propagation Delay Time to Output HIGH Level	I <sub>F</sub> = 7.5mA, V <sub>EH</sub> = 3.5V, R <sub>L</sub> = 350Ω , C <sub>L</sub> = 15pF <sup>(8)</sup> (Fig. 13)			20	ns
t <sub>EHL</sub>	Enable Propagation Delay Time to Output LOW Level	I <sub>F</sub> = 7.5mA, V <sub>EH</sub> = 3.5V, R <sub>L</sub> = 350Ω , C <sub>L</sub> = 15pF <sup>(9)</sup> (Fig. 13)			20	ns
CM <sub>H</sub>	Common Mode Transient Immunity (at Output HIGH Level)	TA = 25 °C,  V <sub>CM</sub>   = 50V (Peak), I <sub>F</sub> = 0mA, V <sub>OH</sub> (Min.) = 2.0V, R <sub>L</sub> = 350Ω(10) (Fig. 14)	5000	10000		V/µs
CM <sub>L</sub>	Common Mode Transient Immunity (at Output LOW Level)	R <sub>L</sub> = 350Ω, I <sub>F</sub> = 7.5mA, VOL (Max.) = 0.8V, TA = 25 °C <sup>(11)</sup> (Fig. 14)	5000	10000		V/µs

## High Speed 10MBit/s Logic Gate Optocouplers

### Electrical Characteristics (Continued)

**Transfer Characteristics ( $T_A = -40$  to  $+85$  °C unless otherwise specified)**

Symbol	DC Characteristics	Test Conditions	Min.	Typ.*	Max.	Unit
$I_{OH}$	HIGH Level Output Current	$V_{CC} = 5.5V$ , $V_O = 5.5V$ , $I_F = 250 \mu A$ , $V_E = 2.0V^{(2)}$			100	$\mu A$
$V_{OL}$	LOW Level Output Current	$V_{CC} = 5.5V$ , $I_F = 5mA$ , $V_E = 2.0V$ , $I_{CL} = 13mA^{(2)}$		0.35	0.6	V
$I_{IT}$	Input Threshold Current	$V_{CC} = 5.5V$ , $V_O = 0.6V$ , $V_E = 2.0V$ , $I_{OL} = 13mA$		3	5	mA

**Isolation Characteristics ( $T_A = -40$  °C to  $+85$  °C unless otherwise specified.)**

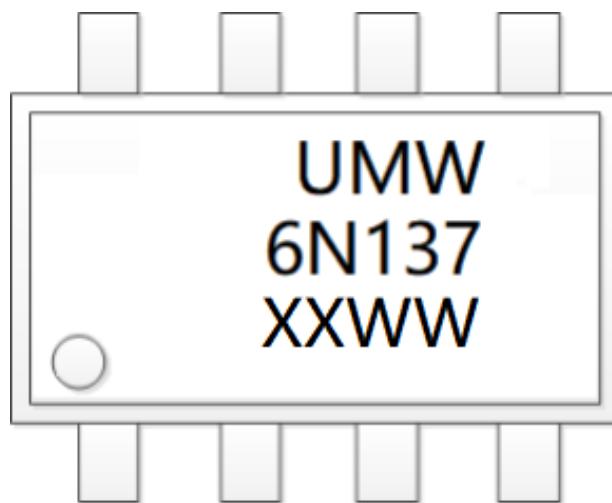
Symbol	Characteristics	Test Conditions	Min.	Typ.*	Max.	Unit
$I_{I-O}$	Input-Output Insulation Leakage Current	Relative humidity = 45%, $T_A = 25$ °C, $t = 5s$ , $V_{I-O} = 3000 VDC^{(12)}$			10*	$\mu A$
$V_{ISO}$	Withstand Insulation Test Voltage	RH < 50%, $T_A = 25$ °C, $I_{I-O} \leqslant 2 \mu A$ , $t = 1$ min. <sup>(12)</sup>	2500			V <sub>RMS</sub>
$R_{I-O}$	Resistance (Input to Output)	$V_{I-O} = 500V^{(12)}$		$10^{12}$		$\Omega$
$C_{I-O}$	Capacitance (Input to Output)	$f = 1MHz^{(12)}$			0.6	pF

\* All Typicals at  $VCC = 5V$

\*  $T_A = 25$  °C

\* Note:

1. The  $V_{CC}$  supply to each optoisolator must be bypassed by a  $0.1 \mu F$  capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package  $V_{CC}$  and GND pins of each device.
2. One channel.
3. Enable Input – No pull up resistor required as the device has an internal pull up resistor.
4.  $t_{PLH}$  – Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
5.  $t_{PHL}$  – Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
6.  $t_r$  – Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
7.  $t_f$  – Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
8.  $t_{ELH}$  – Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
9.  $t_{EHL}$  – Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
10.  $CM_H$  – The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e.,  $V_{OUT} > 2.0V$ ). Measured in volts per microsecond (V/ $\mu s$ ).
11.  $CM_L$  – The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e.,  $V_{OUT} < 0.8V$ ). Measured in volts per microsecond (V/ $\mu s$ ).
12. Device considered a two-terminal device: Pins 1, 2, 3 and 4 shorted together, and Pins 5, 6, 7 and 8 shorted together.

**Marking**

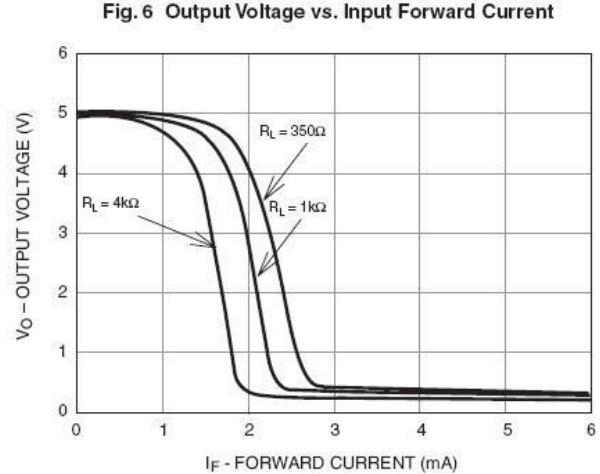
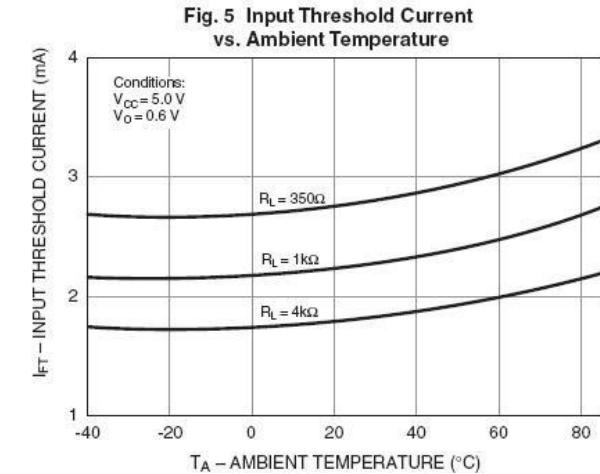
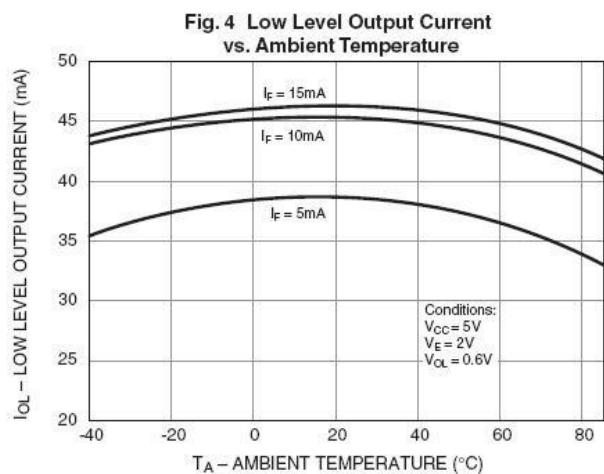
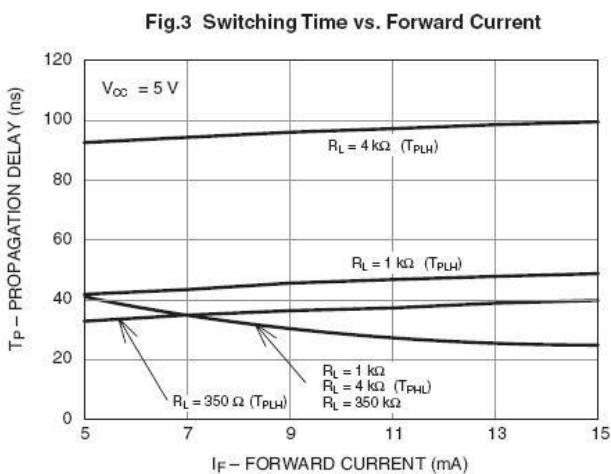
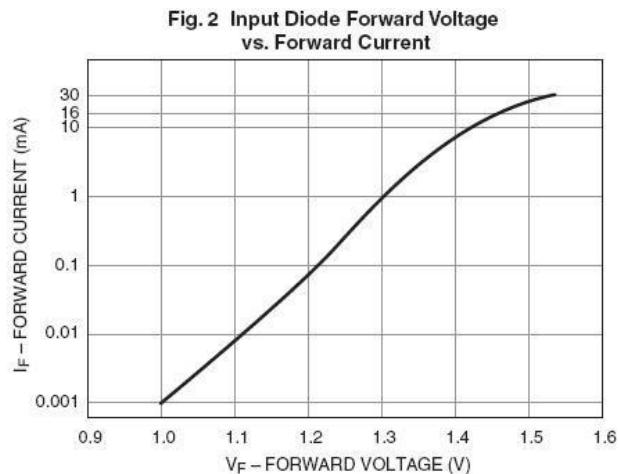
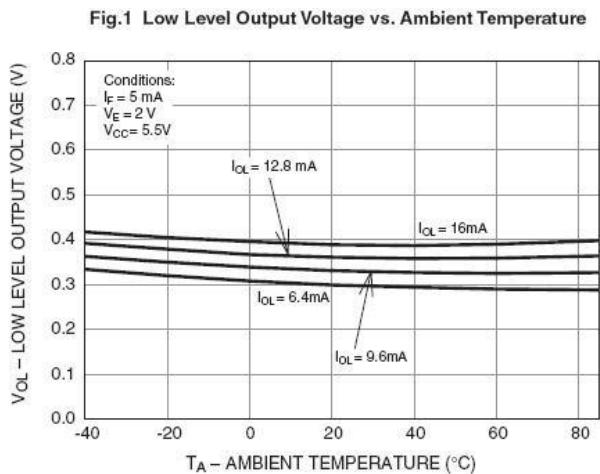
- “XX” denotes YEAR;
- “WW” denotes WEEK

**Order Code**

Order Code	Description	Base qty
UMW 6N137M	Iron frame, DIP, Halogen/lead -free	2250/BOX
UMW 6N137S	Copper frame,SOP-8, Halogen -free	1000/REEL

## High Speed 10MBit/s Logic Gate Optocouplers

### Typical Performance Curves



## High Speed 10MBit/s Logic Gate Optocouplers

### Typical Performance Curves (Continued)

Fig. 7 Pulse Width Distortion vs. Temperature

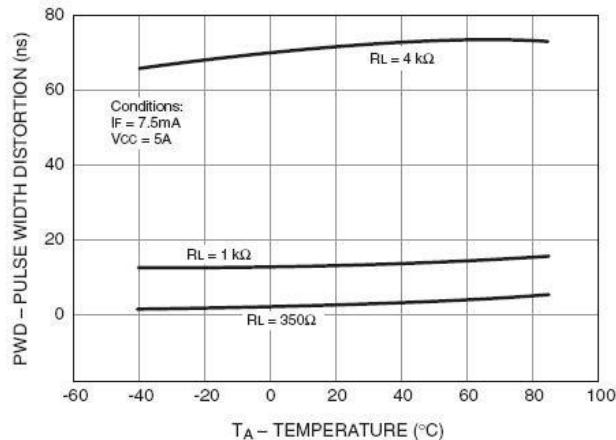


Fig. 8 Rise and Fall Time vs. Temperature

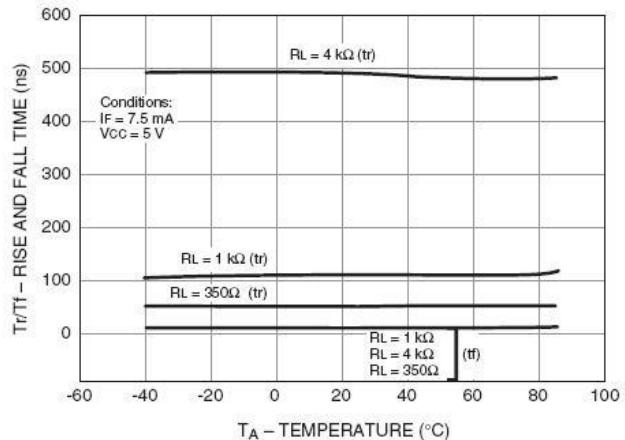


Fig. 9 Enable Propagation Delay vs. Temperature

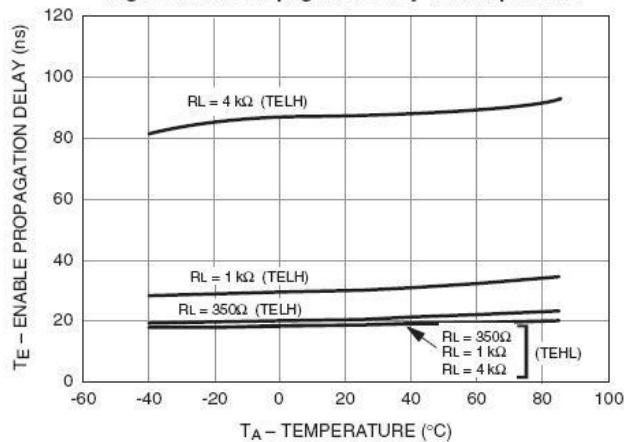


Fig. 10 Switching Time vs. Temperature

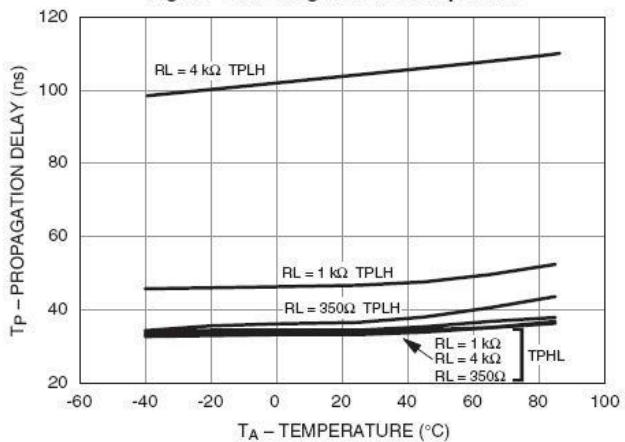
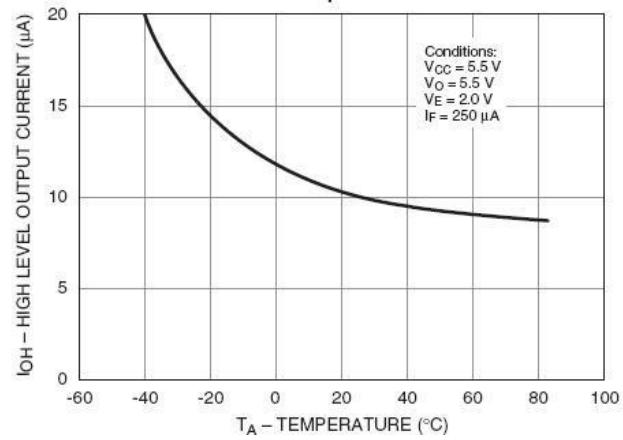


Fig. 11 High Level Output Current vs. Temperature



## High Speed 10MBit/s Logic Gate Optocouplers

### Test Circuits

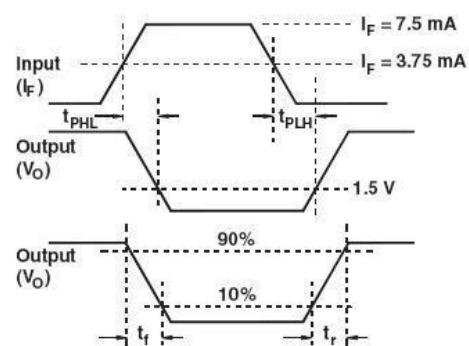
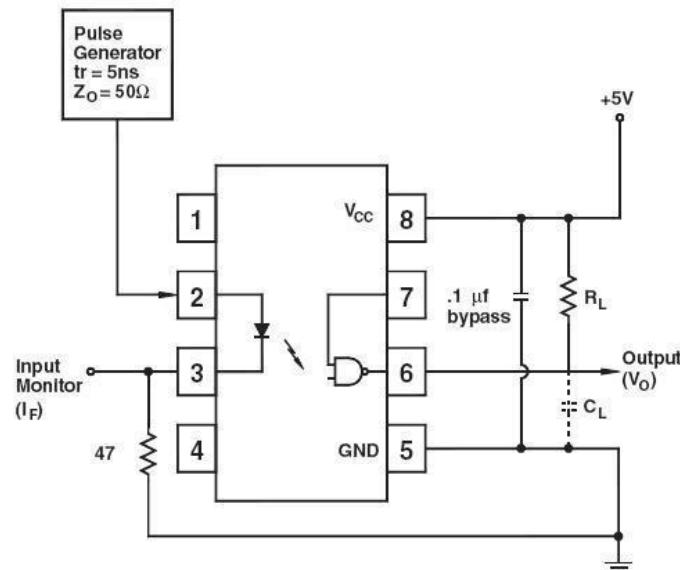


Fig. 12 Test Circuit and Waveforms for  $t_{PLH}$ ,  $t_{PHL}$ ,  $t_f$  and  $t_r$

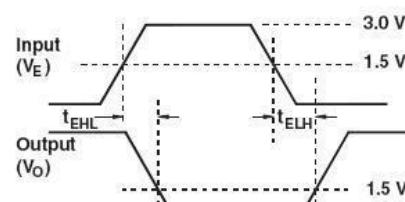
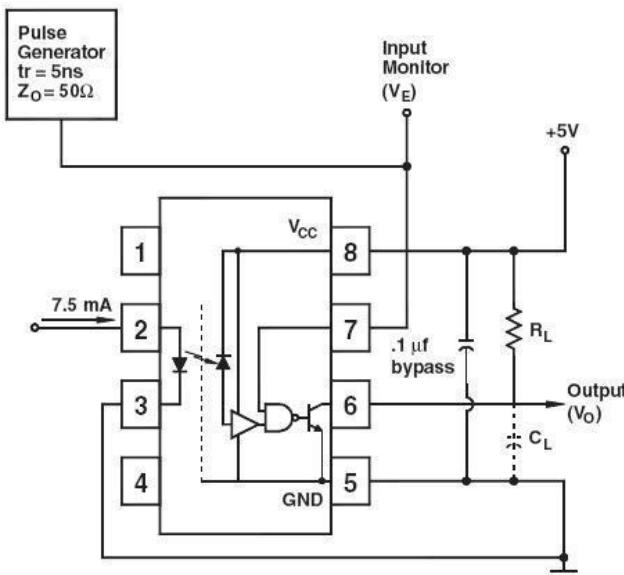


Fig. 13 Test Circuit  $t_{EHL}$  and  $t_{ELH}$

## High Speed 10MBit/s Logic Gate Optocouplers

## Test Circuits (Continued)

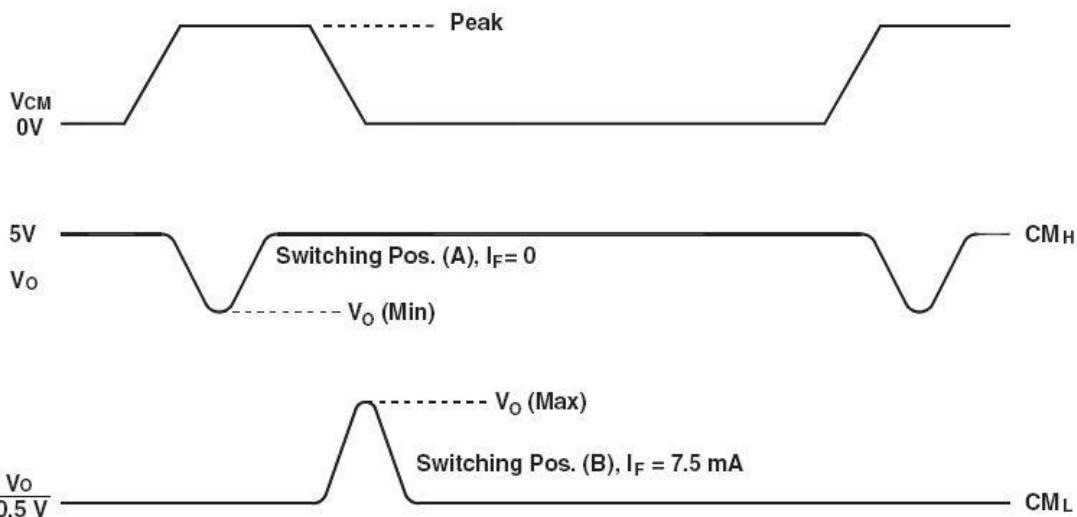
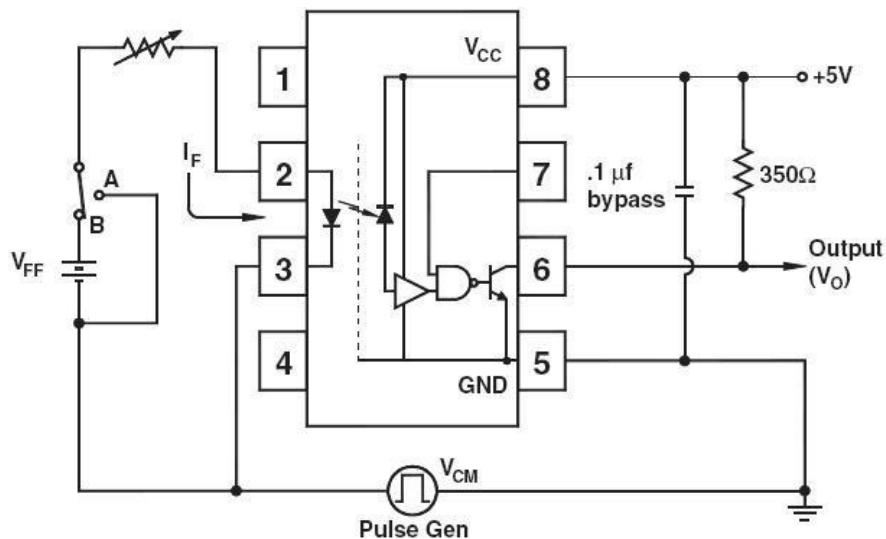
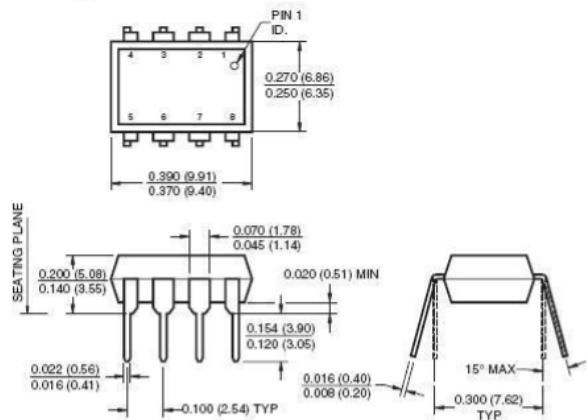


Fig. 14 Test Circuit Common Mode Transient Immunity

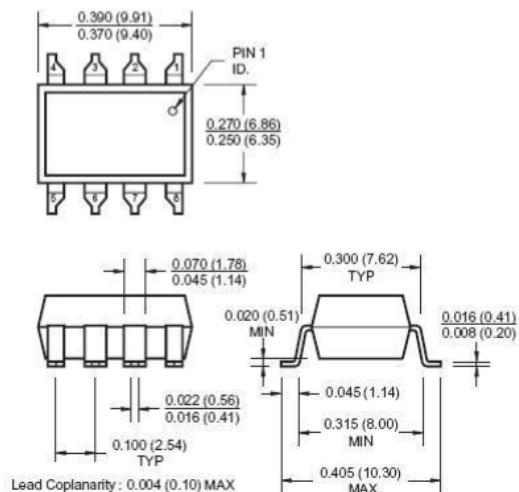
## High Speed 10MBit/s Logic Gate Optocouplers

### Package Dimensions

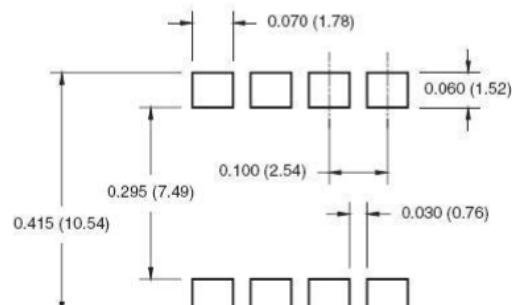
#### Through Hole



#### Surface Mount



#### 8-Pin DIP – Land Pattern



Note: All dimensions are in inches (millimeters)

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[TLP5772H\(D4LF4,E](#) [TLP5774H\(LF4,E](#) [TLP5771H\(D4LF4,E](#) [TLP5771H\(LF4,E](#) [TLP5214A\(E\(O](#) [FOD3125SD](#) [FOD8482T](#) [LTV-3120S-](#)  
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[H11L3SR2M](#) [HCPL-0302-000E](#) [HCPL-J312-000E](#) [LTV-3120S-TA1](#) [TLP155E\(TPL,E\)](#) [TLP2345\(E\(T](#) [TLP2348\(E\(T](#) [TLP350H\(F\)](#)  
[TLP5214\(E\(O](#) [TLP701AF\(F\)](#)